

RFMD + TriQuint = Qorvo

TGA4544-SM

26 - 31 GHz 1W Power Amplifier

Applications

- · Point-to-Point Radio
- Ka-band Sat-Com



26 lead 5x5mm ACQFN package

Product Features

Frequency Range: 26 – 31 GHz
Power: 32 dBm Psat, 31 dBm P1dB

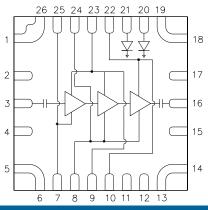
• Gain: 23 dB

TOI: 41 dBm at 20 dBm/tone
Integrated Power Detector

 Bias: Vd = 6 V, Idq = 1100 mA, Vg = -0.58 V Typical

• Package Dimensions: 5.0 x 5.0 x 1.3 mm

Functional Block Diagram



General Description

The TriQuint TGA4544-SM is a Ka-Band Power Amplifier with integrated power detector. The TGA4544-SM operates from 26 – 31 GHz and is designed using TriQuint's power pHEMT production process.

The TGA4544-SM typically provides 32 dBm of saturated output power with small signal gain of 23 dB. Third Order Intercept is 41 dBm at 20 dBm SCL.

The TGA4544-SM is available in a low-cost, surface mount 26 lead 5x5 ACQFN package and is ideally suited for Point-to-Point Radio.

Lead-free and RoHS compliant

Evaluation Boards are available upon request.

Pin Configuration

Pin No.	Label
1, 2, 4, 5, 6, 12, 13, 14, 15, 17, 18, 19, 26	GND
3	RF IN
7, 25	VG1
8, 24	VG23
9, 23	VD12
10, 22	VD3
11	NC
16	RFOUT
20	VDET
21	VREF

Ordering Information

Part No.	ECCN	Description
TGA4544-SM	3A001.b.2.d	26 – 31 GHz 1W Power Amplifier

Standard T/R size = 200 pieces on a 7" reel

TGA4544-SM

26 - 31 GHz 1W Power Amplifier

Absolute Maximum Ratings

Parameter	Rating
Drain Voltage,Vd	6.5 V
Gate Voltage,Vg	-3.5 to 0 V
Drain to Gate Voltage, Vd – Vg	10 V
Drain Current, Id	2.5 A
Gate Current, Ig	-7 to +52 mA
Power Dissipation, Pdiss	16.2 W
RF Input Power, CW, T = 25 °C	25 dBm
Channel Temperature, Tch	200 °C
Mounting Temperature (30 sec)	260 °C
Storage Temperature	-40 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage.

Recommended Operating

Parameter	Min	Тур	Max	Units
Operating Temp. Range	-40		+85	°C
Vd		6.0		V
ldq		1100		mA
Id_drive		1536		mA
Vg		-0.58		V
Ig_drive (Under RF Drive)		12		mA

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: Vd =+6 V, Idq = 1100 mA, Vg =-0.58 V, Temp= +25°C, $Z_0 = 50 \Omega$

Parameter	Conditions	Min	Тур	Max	Units
Operational Frequency Range		26		31	GHz
Gain			23		dB
Input Return Loss			8		dB
Output Return Loss			10		dB
Output Power @ Saturation			32		dBm
Output Power @ 1 dB Gain Compression			31		dBm
Output TOI @ 20 dBm/Tone Pout/tone			41		dBm
Gain Temperature Coefficient			-0.03		dB/°C
Power Temperature Coefficient			-0.01		dBm/°C

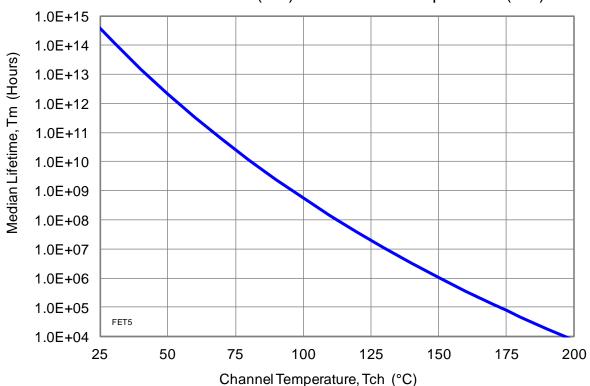


Specifications

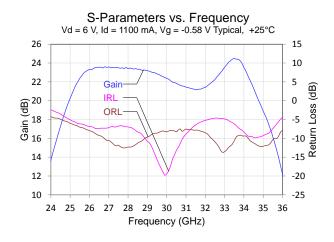
Thermal and Reliability Information

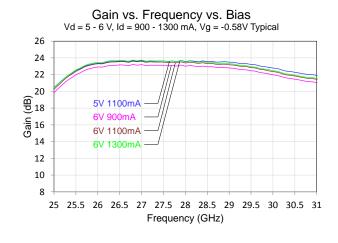
Parameter	Conditions	Rating
Thermal Resistance, $\theta_{\text{JC}},$ measured to back of package	Tbase = 85 °C	$\theta_{JC} = 10 ^{\circ}\text{C/W}$
Channel Temperature (Tch), and Median Lifetime (Tm)	Tbase = 85 °C Vd = 6 V Id = 1100 mA Pdiss = 6.6 W	Tch = 151 °C Tm = 9.3E+5 Hours

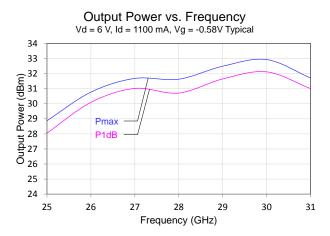
Median Lifetime (Tm) vs. Channel Temperature (Tch)

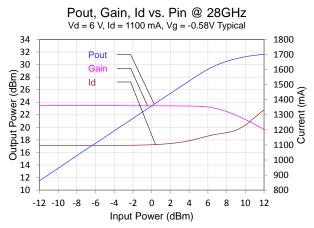


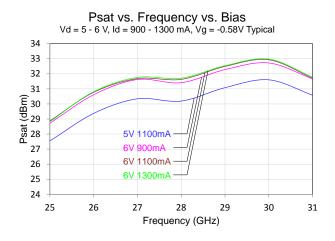
Typical Performance

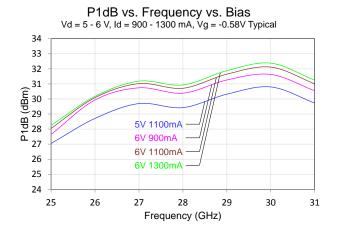








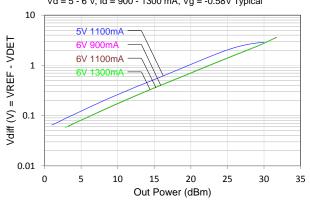




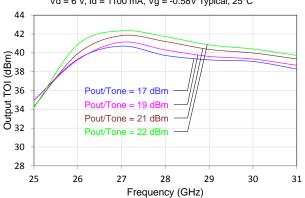


Typical Performance

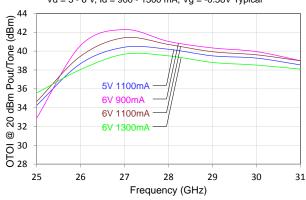
Power Detector vs. Pout vs. Bias @ 28GHz Vd = 5 - 6 V, Id = 900 - 1300 mA, Vg = -0.58V Typical



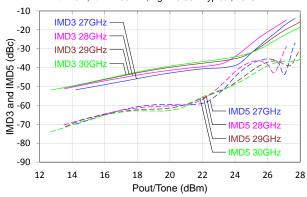
Output TOI vs. Frequency Vd = 6 V, Id = 1100 mA, Vg = -0.58V Typical, 25°C



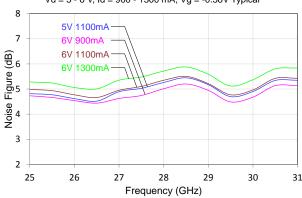
Output TOI vs. Frequency vs. Bias Vd = 5 - 6 V, Id = 900 - 1300 mA, Vg = -0.58V Typical



IMD3 and IMD5 vs. Pout/Tone vs. Frequency Vd = 6 V, Id = 1100 mA, Vg = -0.58V Typical, 25°C



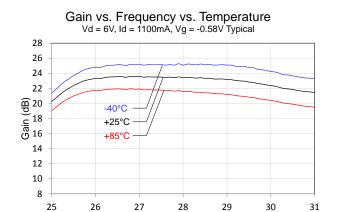
Noise vs. Frequency vs. Bias Vd = 5 - 6 V, Id = 900 - 1300 mA, Vg = -0.58V Typical

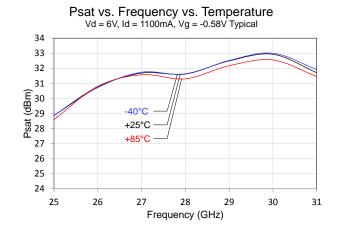


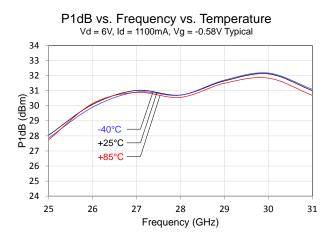
-5 of 14 -



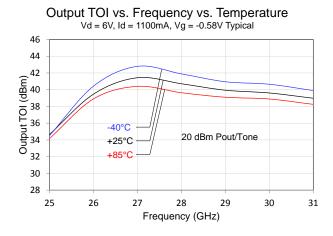
Typical Performance

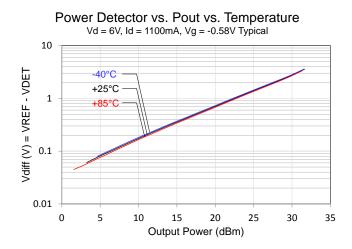






Frequency (GHz)

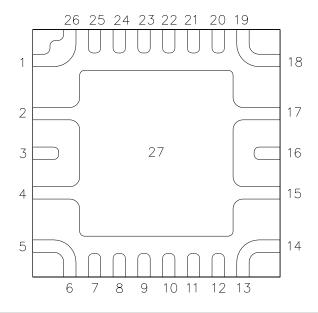




-6 of 14 -

26 - 31 GHz 1W Power Amplifier

Pin Configuration and Description

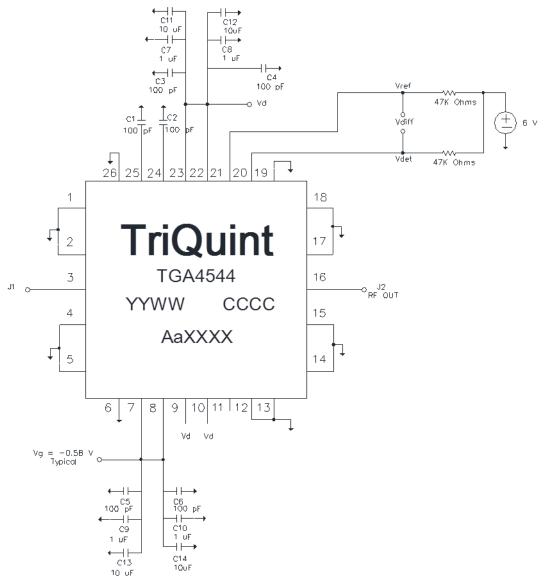


Pin No.	Label	Description
1, 5, 6, 13 14, 18, 19, 26	GND	Must be connected to Ground
2, 4, 15, 17, 27	GND	Backside paddle. Multiple vias should be employed to minimize inductance and thermal resistance; see 'PCB Mounting Pattern' on page 11 for suggested footprint
3	RF IN	RF input, matched to 50 ohms
7, 25	VG1	Stage 1 gate voltage (1)
8, 24	VG23	Stage 2 and 3 gate voltage (1)
9, 23	VD12	Stage 1 and 2 drain voltage
10, 22	VD3	Stage 3 drain voltage
11	NC	No internal connection; Can be grounded on PCB or left open
12	GND	Internally connected to GND. Can be grounded on the PCB or left open
16	RF OUT	RF output, matched to 50 ohms
20	VDET	Detector diode output voltage. Varies with RF output power
21	VREF	Reference diode output voltage

⁽¹⁾ Bias bypass network is required; see 'Application Circuit' on page 8 as an example.



Application Circuit



Vd can be biased from either side (pin 9, 10 or pin 21, 22)

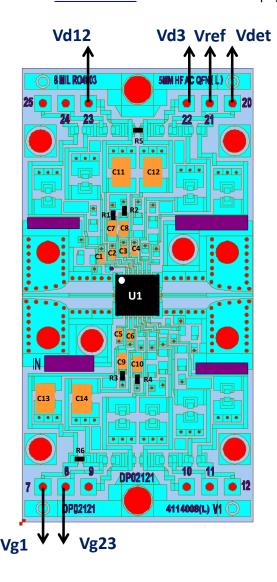
Bias-up Procedure	Bias-down Procedure
Vg set to -1.5 V	Turn off RF supply
Vd set to +6 V	Reduce Vg to -1.5 V. Ensure Id ~ 0 mA
Adjust Vg more positive until quiescent Id is 1100 mA. This will be ~ Vg = -0.58 V typical	Turn Vd to 0 V
Apply RF signal to RF Input	Turn Vg to 0 V



Application Circuit

PC Board Layout

Board material is Rogers Corp. 4003 0.008" thickness with ½ oz copper cladding. For further technical information, refer to the TGA4544-SM Product Information page.



Bill of Material

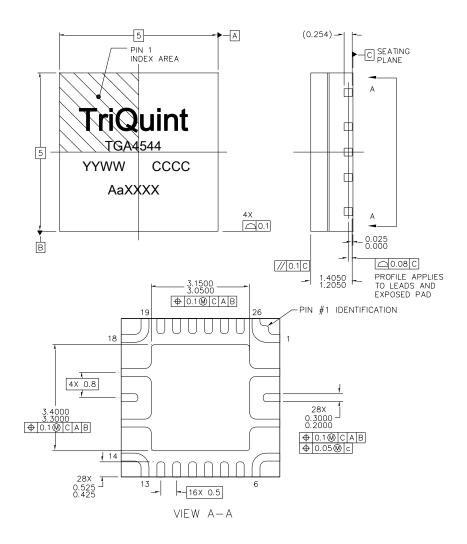
Ref Des	Value	Description	Manufacturer	Part Number
U1		Ka Band Power Amplifier	TriQuint	TGA4544-SM
C1 thru C6	100.0 pF	Cap, 0402, 20V, 5%, COG	various	
C7 thru C10	1.0 µF	Cap, 0603/0805, 25V, 5%, COG	various	
C11 thru C14	10.0 μF	Cap, 0805, 25V, COG	various	
R1 thru R6	0 Ω	Res. 0402, 1/16 W, 5% SMT	various	



Mechanical Information

Package Marking and Dimensions

All dimensions are in millimeters.



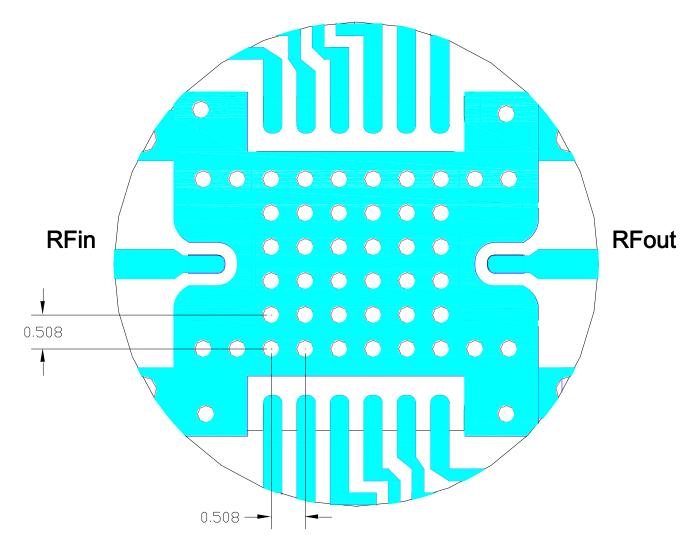
The TGA4544-SM will be marked with the "YYWW" designator and a lot code marked below the part designator. The "YY" represents the last two digits of the year the part was manufactured, the "WW" is the work week, the "CCCC" is the country code, the "Aa" is the vendor, and the "XXXX" is the last 4 digit of lot number.

This package is lead-free/RoHS-compliant with a copper alloy base (CDA194), and the plating material on the leads is NiPdAu. It is compatible with lead-free (maximum 260 °C reflow temperature) soldering process.



Mechanical Information

PCB Mounting Pattern



Notes:

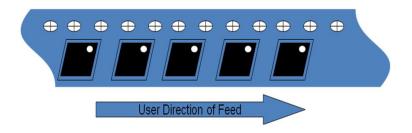
- The pad pattern shown has been developed and tested for optimized assembly at TriQuint Semiconductor. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.
- 2. Ground vias are critical for the proper performance of this device. Vias have a final plated thru diameter of .25 mm (.010").

26 - 31 GHz 1W Power Amplifier

Tape and Reel Information

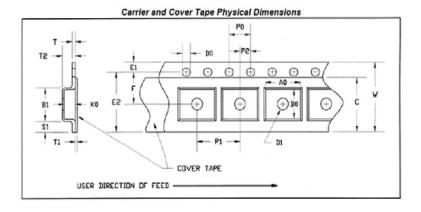
Standard T/R size = 200 pieces on a 7" reel

Vendor: Tek-Pak P/N QFN0500x0500F-L500



CARRIER AND COVER TAPE DIMENSIONS

Part	Feature	Symbol	Size (in)	Size (mm)
Cavity	Length	A0	0.209	5.3
	Width	B0	0.209	5.3
	Depth	K0	0.064	1.65
	Pitch	P1	0.315	8.00
Cover Tape	Width	С	0.362	9.2
Carrier Tape	Width	W	0.472	12.00



RFMD + TriQuint = Qorvo

TGA4544-SM

26 – 31 GHz 1W Power Amplifier

Product Compliance Information

ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: Class 1A

Value: Passed ≥ 300 V min.

Test: Human Body Model (HBM)

Standard: JEDEC Standard JESD22-A114

MSL Rating

MSL Rating: Level 3

Test: 260°C convection reflow

Standard: JEDEC Standard IPC/JEDEC J-STD-020

Solderability

Compatible with lead-free (260°C maximum reflow temperature).

Package lead plating: NiPdAu.

The use of no-clean solder to avoid washing after soldering is recommended.

This package is not compatible with solder containing lead.

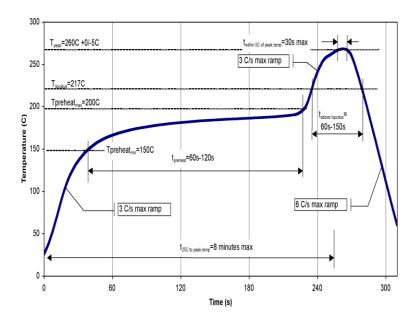
RoHs Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Recommended Solder Temperature Profile



TGA4544-SM

26 - 31 GHz 1W Power Amplifier

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.triquint.com Tel: 1-844-890-8163

Email: customer.support@gorvo.com

For information about the merger of RFMD and TriQuint as Qorvo:

Web: <u>www.qorvo.com</u>

For technical questions and application information: Email: info-networks@tgs.com

Important Notice

The information contained herein is believed to be reliable. TriQuint makes no warranties regarding the information contained herein. TriQuint assumes no responsibility or liability whatsoever for any of the information contained herein. TriQuint assumes no responsibility or liability whatsoever for the use of the information contained herein. The information contained herein is provided "AS IS, WHERE IS" and with all faults, and the entire risk associated with such information is entirely with the user. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for TriQuint products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information.

TriQuint products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.